Title: III-V GROUP NITRIDE SYSTEM SEMICONDUCTOR SUBSTRATE Inventor(s): Masatomo SHIBATA DOCKET NO.: 035532-0138

FIG. 1

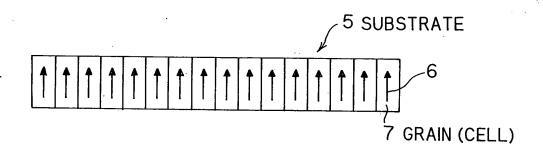


FIG. 2

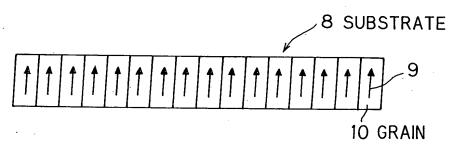
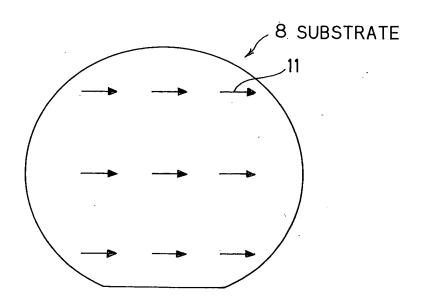


FIG. 3



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 $\mathcal{C}$ 

FIG. 4 PRIOR ART

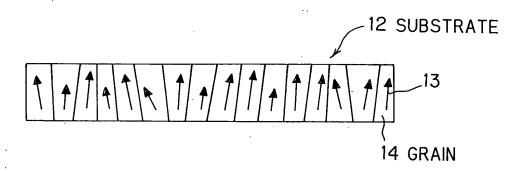
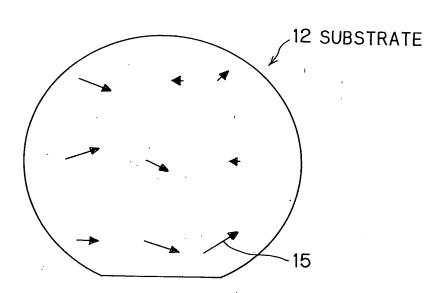


FIG. 5 PRIOR ART



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FIG. 6

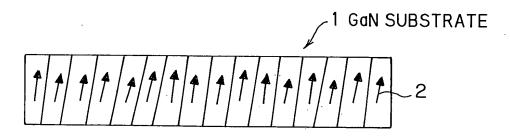


FIG. 7

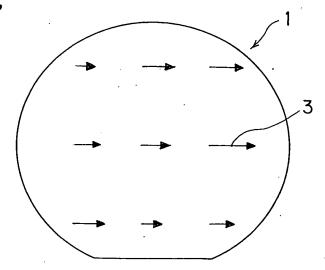
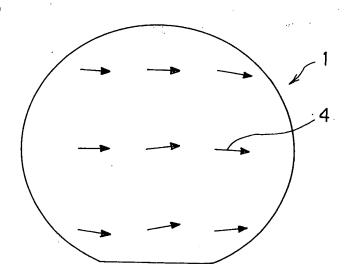


FIG. 8



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FIG. 9

